

晶体管 TRANSISTOR A1015A

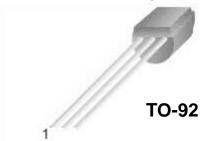
主要参数 MAIN CHARACTERISTICS

Ic	-150mA
Vceo	-50V
Vсво	-50V
Pc	400mW

用途 APPLICATIONS

高频开关电源	High frequency switch
	power supply
一般功率放大电路	Commonly power amplifier
	circuit
高频功率变换	High frequency power
	transform

封装形式 Package



1.Emitter 2.Collecto 3.Base

绝对最大额定值 ABSOLUTE RATINGS(Tc=25℃)

项目 Parameter	符号 Symbol	数值 Value	单位 Unit
集电极—基极直流电压 Collector- Base Voltage (IE=0)	Vсво	-50	V
集电极—发射极直流电压 Collector- Emitter Voltage(IB=0)	VCEO	-50	V
发射极—基极直流电压 Emitter-Base Voltage(IC=0)	VEBO	-5	V
最大集电极直流电流 Collector Current(DC)	Ic	-150	mA
最大集电极耗散功率 Total Dissipation (TO-92)	Pc	400	mW
最高结温 Junction Temperature	Tj	150	$^{\circ}$ C
贮存温度 Storage Temperature	Tstg	-55~+150	$^{\circ}$ C

产品特性 FEATURES

硅外延	Epitaxial silicon
高开关速度	High switching speed
与 2SC1815 互补	Complementary to 2SC1815
RoHS 产品	RoHS product

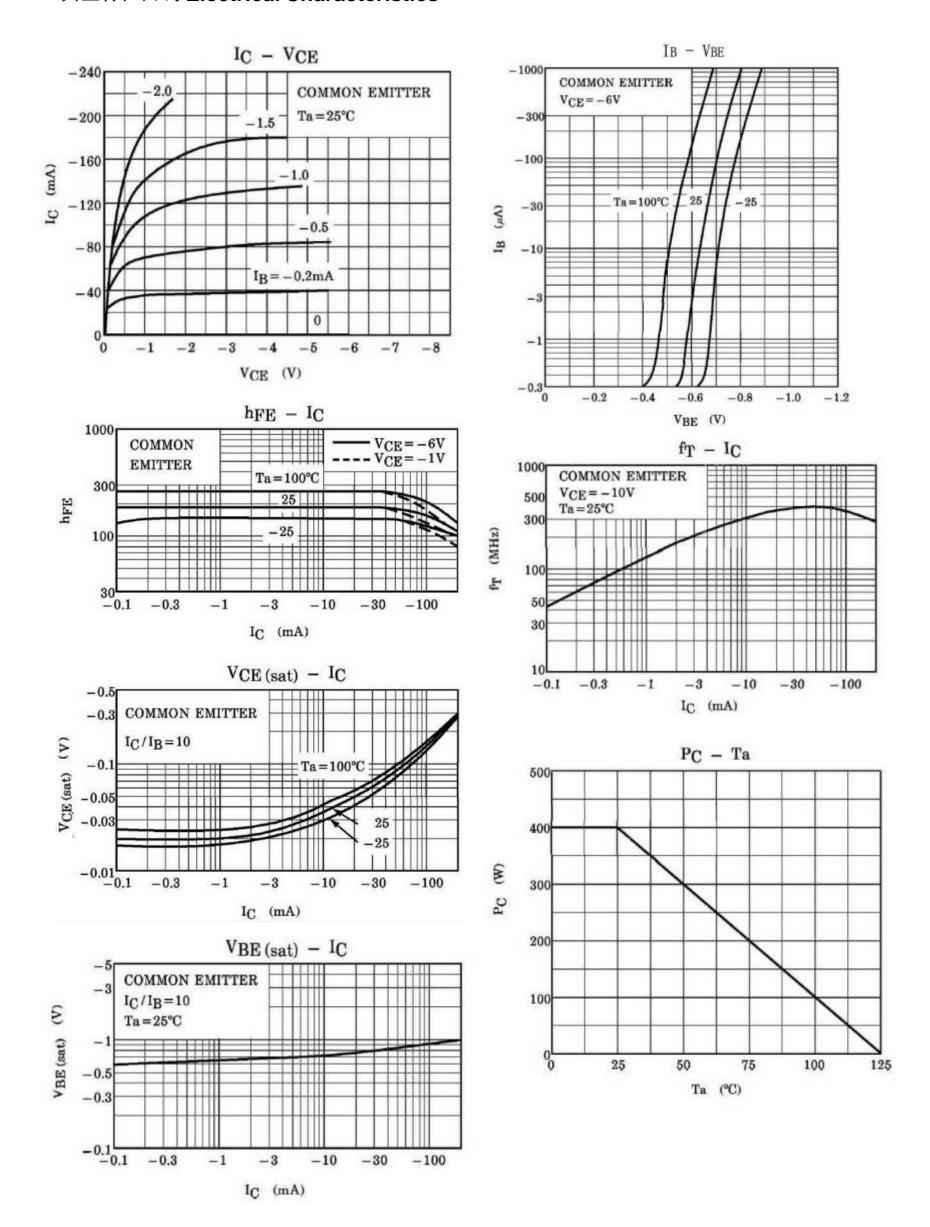
电特性 ELECTRICAL CHARACTERISTICS

项目 Parameter	测试条件 Tests conditions	最小值 (min)	典型值 (typ)	最大值 (max)	单位 Unit
V(BR)cво	Ic=-100uA,IE=0	-50	-	-	٧
V(BR)CEO	Ic=-2mA,IB=0	-50		-	V
V(BR)EBO	IE=-100uA,IC=0	-5	-	-	V
Ісво	Vcb=-50V, IE=0	-	-	-0.1	μA
І ЕВО	VEB=-5V, IC=0	-	-	-0.1	μA
Hfe(1)	VCE =-6V, IC=-2mA	70	-	400	-
Hfe(2)	VCE =-6V, IC=-150mA	25	-	-	-
VCE(sat)	Ic=-100mA, IB=-10mA	-	-	-0.3	V
VBE(sat)	Ic=-100mA, IB=-10mA	-	-	-1.1	V

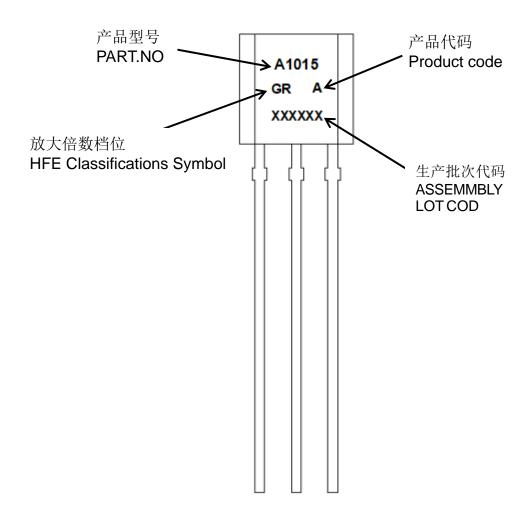
放大倍数hfe Classifications

hFE Classifications Symbol	0	Y	GR
hfe Range	70-140	120-240	200-400

典型特性曲线 Electrical Characteristics

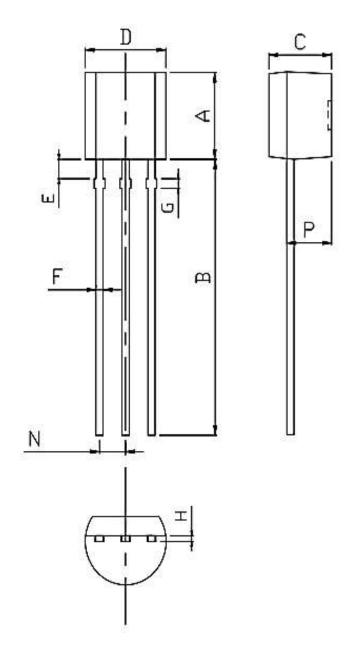


印记 Marking:



外形尺寸: Package Dimension

T0-92



DIM	MILLIMETERS
Α	4. 55+0. 20
В	14.50±0.30
С	3.54±0.20
D	4.56±0.20
Е	1.30±0.20
F	0.46±0.20
G	0.50±0.10
Н	0.32±0.10
N	1.30±0.20
P	2.52±0.20

Unit: (mm)